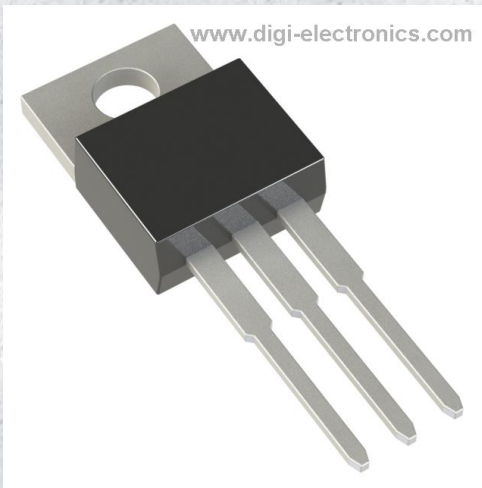


IXTP110N12T2 Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	IXTP110N12T2-DG
Manufacturer	IXYS
Manufacturer Product Number	IXTP110N12T2
Description	MOSFET N-CH 120V 110A TO220AB
Detailed Description	N-Channel 120 V 110A (Tc) 517W (Tc) Through Hole TO-220-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

IXTP110N12T2

Series:

TrenchT2™

FET Type:

N-Channel

Drain to Source Voltage (Vdss):

120 V

Drive Voltage (Max Rds On, Min Rds On):

10V

Vgs(th) (Max) @ Id:

4.5V @ 250µA

Vgs (Max):

±20V

FET Feature:

-

Operating Temperature:

-55°C ~ 175°C (Tj)

Supplier Device Package:

TO-220-3

Base Product Number:

IXTP110

Manufacturer:

IXYS

Product Status:

Obsolete

Technology:

MOSFET (Metal Oxide)

Current - Continuous Drain (Id) @ 25°C:

110A (Tc)

Rds On (Max) @ Id, Vgs:

14mOhm @ 55A, 10V

Gate Charge (Qg) (Max) @ Vgs:

120 nC @ 10 V

Input Capacitance (Ciss) (Max) @ Vds:

6570 pF @ 25 V

Power Dissipation (Max):

517W (Tc)

Mounting Type:

Through Hole

Package / Case:

TO-220-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we stricly control the quality of products and services. Welcome your RFQ to

Email: Info@DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.